

## Table of Contents

<b>Subgrain Boundaries in ZMR Silicon</b> E. Goo	1
<b>Introduction of Dislocations into High-<math>T_c</math> Superconductors</b> X.G. Zheng and Y. Tomokiyo	7
<b>The Long-Range Order and Defect Structures in B2 NiAl Type and L1<sub>2</sub>Ni<sub>3</sub>Al and Al<sub>3</sub>Ti-X Type Intermetallic Compounds</b> M. Kogachi	15
<b>New Semimagnetic Semiconductors: HgS Doped with Transition Metals</b> K. Dybko, W. Szuszkiewicz and B. Witkowska	41